



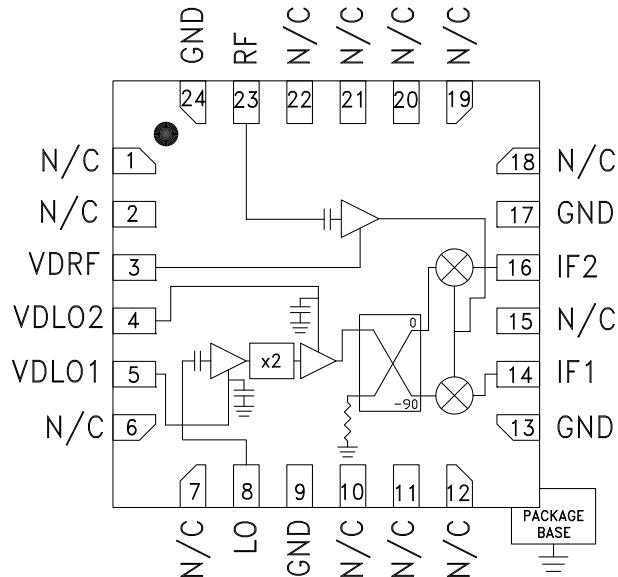
GaAs MMIC I/Q DOWNCONVERTER 17 - 20 GHz

Typical Applications

The HMC966LP4E is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications

Functional Diagram



Electrical Specifications, $T_A = +25^\circ\text{C}$, IF = 1000 MHz, LO = +6 dBm, Vdd = 3.5 Vdc LSB [1]

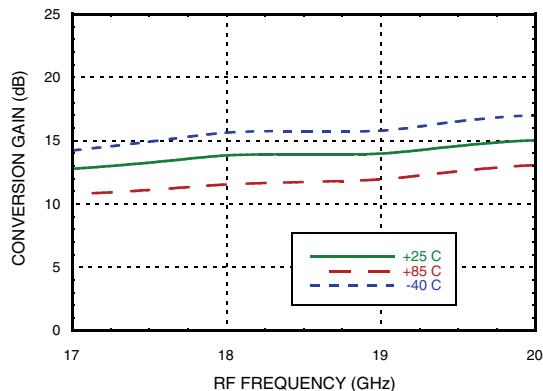
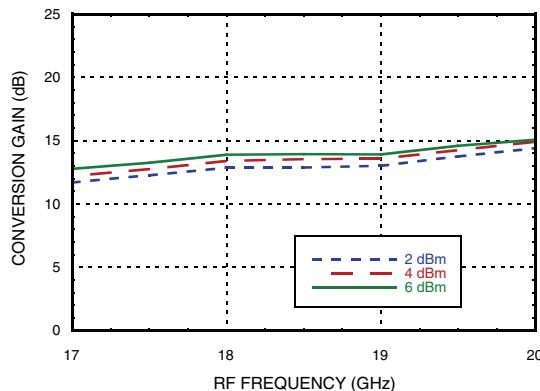
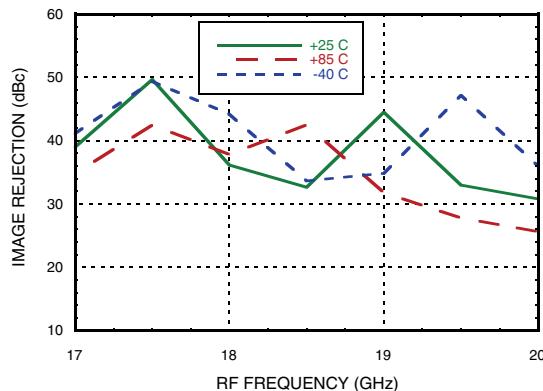
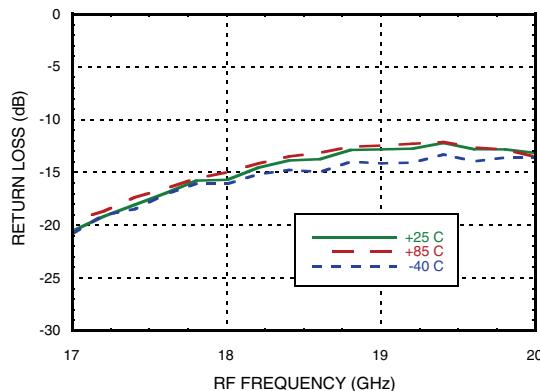
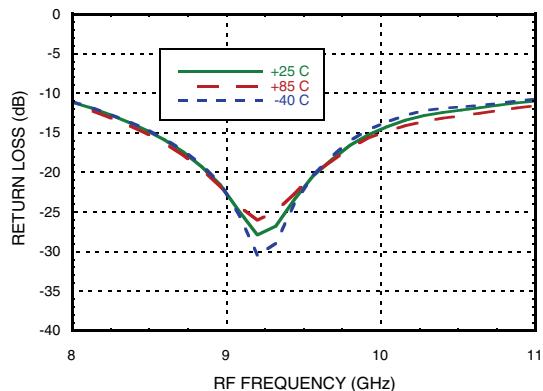
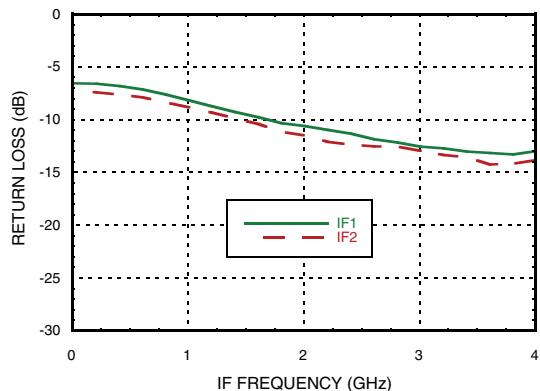
Parameter	Min.	Typ.	Max.	Units
Frequency Range, RF		17 - 20		GHz
Frequency Range, LO		7.5 - 11.75		GHz
Frequency Range, IF		DC - 3.5		GHz
Conversion Gain (As IRM)	10	14		dB
Noise Figure		2.5	3.5	dB
Image Rejection	15	40		dBc
1 dB Compression (Input)		-9		dBm
2 LO to RF Isolation	38	47		dB
2 LO to IF Isolation	9	14		dB
IP3 (Input)	-2	0		dBm
Amplitude Balance [2]		0.5		dB
Phase Balance [2]		17		deg
Total Supply Current		160	200	mA

[1] Data taken as IRM with external IF 90° Hybrid

[2] Data taken without external 90° hybrid, IF = 1000 MHz


**GAAS MMIC I/Q DOWNCONVERTER
17 - 20 GHz**

Data Taken As IRM With External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain LSB vs. Temperature

Conversion Gain LSB vs. LO Drive

Image Rejection vs. Temperature

RF Return Loss vs. Temperature

LO Return Loss vs. Temperature

IF Return Loss [1]


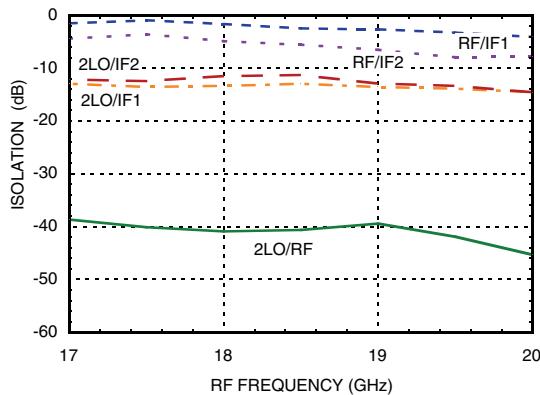
[1] Data taken without external 90° hybrid.



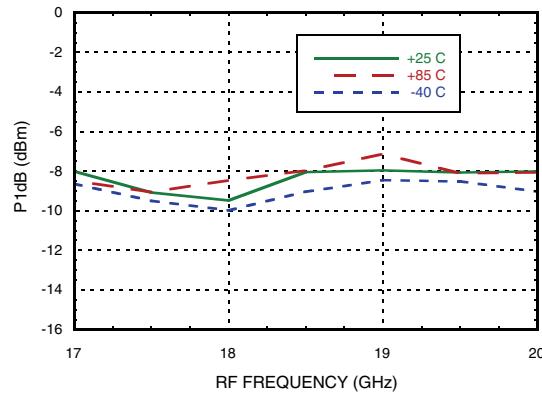
GAAS MMIC I/Q DOWNCONVERTER 17 - 20 GHz

Data Taken as IRM With External IF 90° Hybrid, IF = 1000 MHz

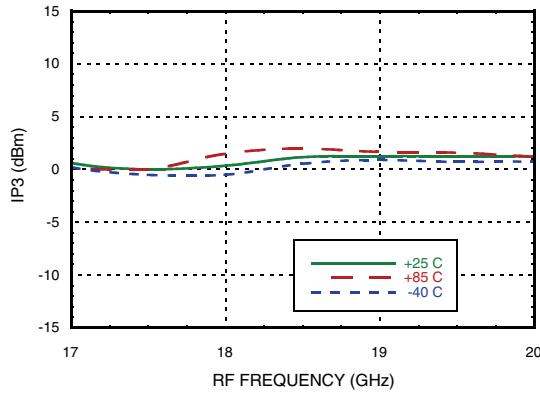
Isolations



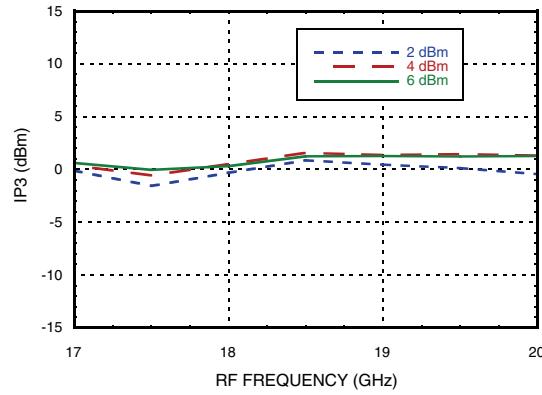
Input P1dB LSB vs. Temperature



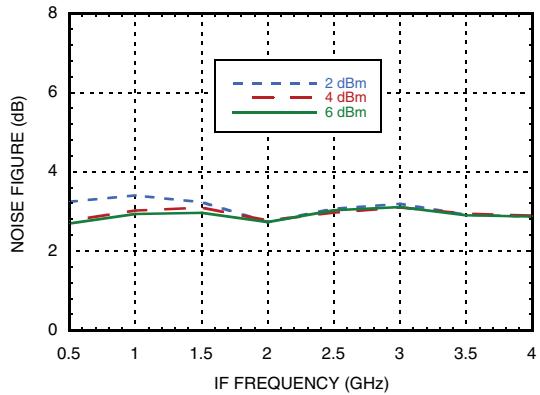
Input IP3, LSB vs. Temperature



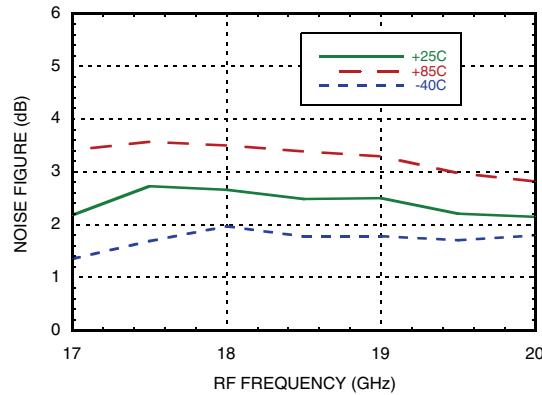
Input IP3, LSB vs. LO Drive



Noise Figure vs. LO Drive, LO Frequency = 8.25 GHz

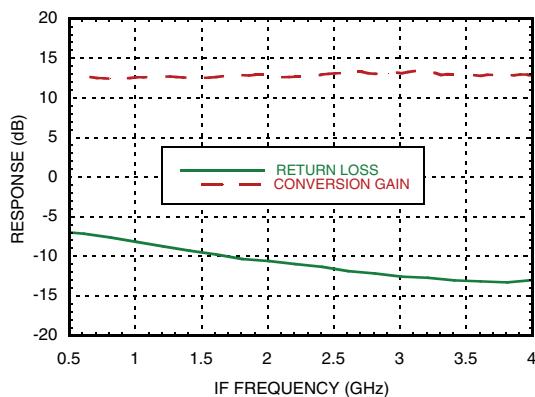
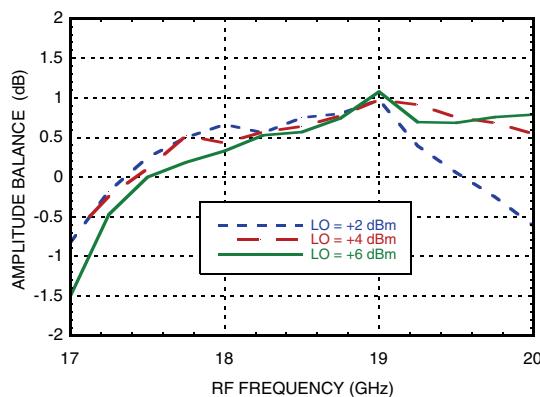
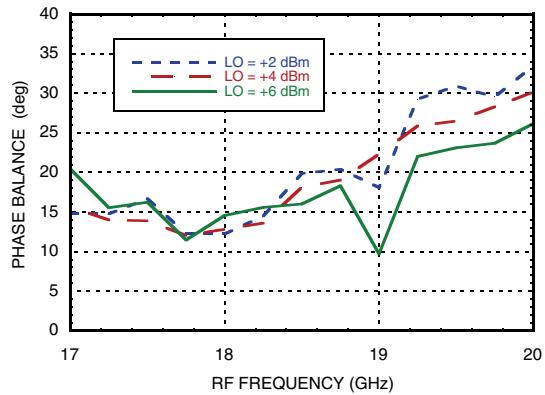


Noise Figure vs. Temperature, IF Frequency = 1000 MHz




**GAAS MMIC I/Q DOWNCONVERTER
17 - 20 GHz**

Quadrature Channel Data Taken Without IF 90° Hybrid, IF = 1000 MHz

IF Bandwidth [1]

Amplitude Balance vs. LO Drive [2]

Phase Balance vs. LO Drive [2]


[1] Data taken with LO frequency fixed at 6.5 GHz and RF varied.

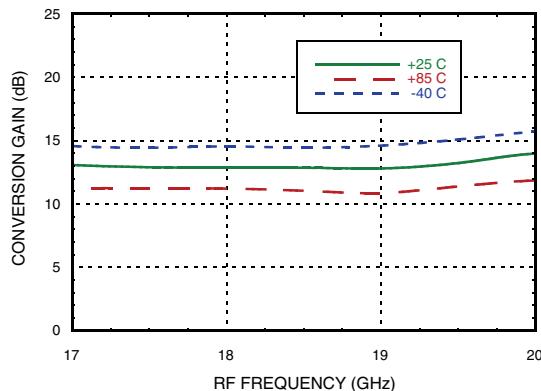
[2] Data taken with IF = 1000 MHz



GAAS MMIC I/Q DOWNCONVERTER 17 - 20 GHz

Data Taken as IRM With External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

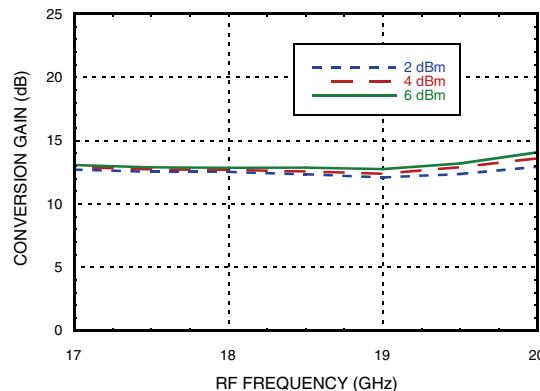
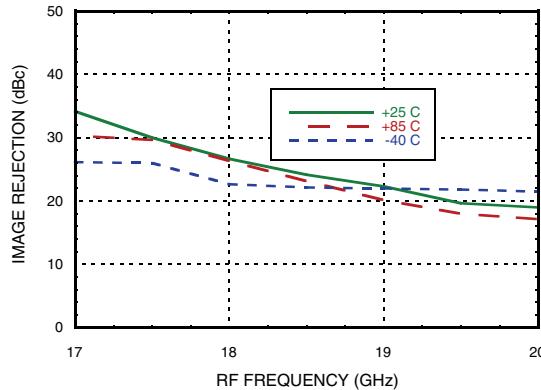
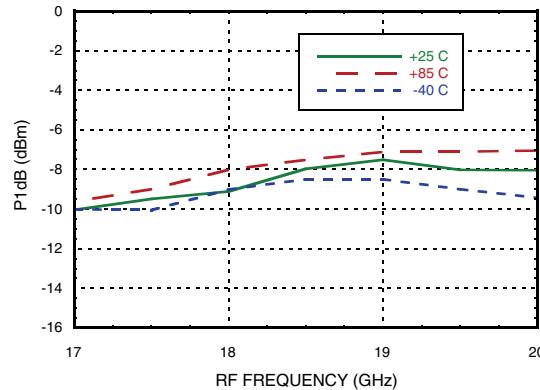


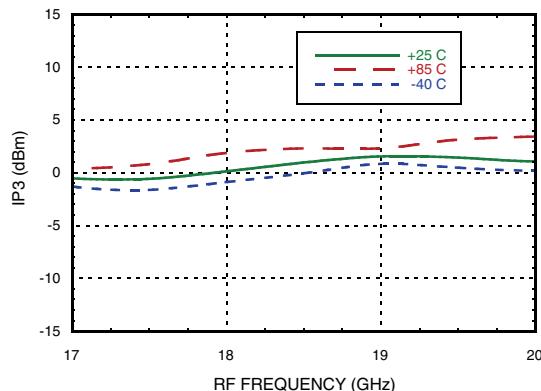
Image Rejection vs. Temperature



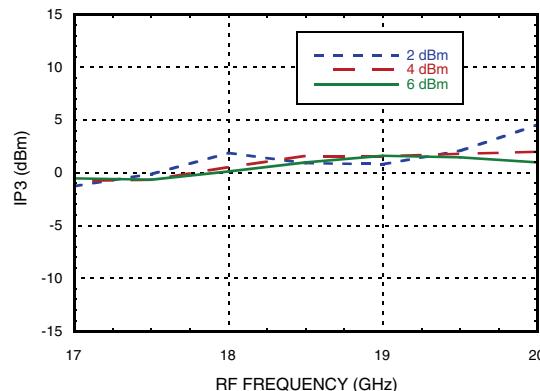
Input P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature

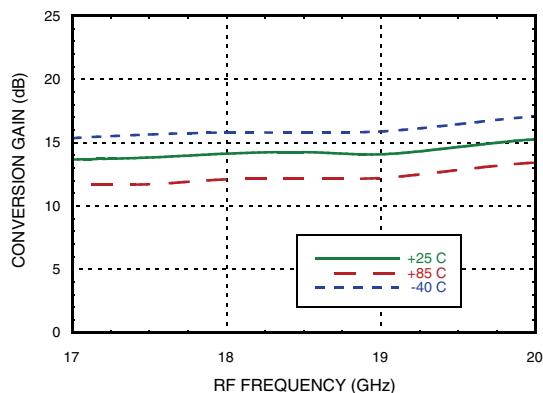
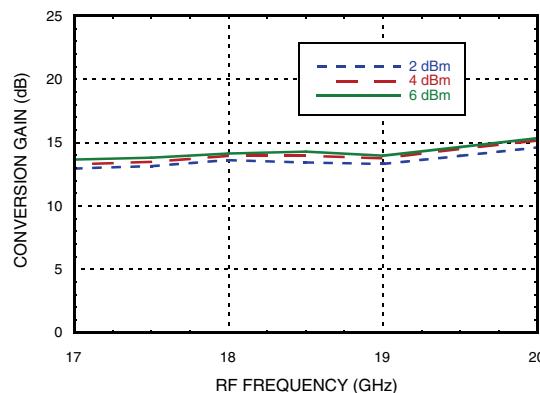
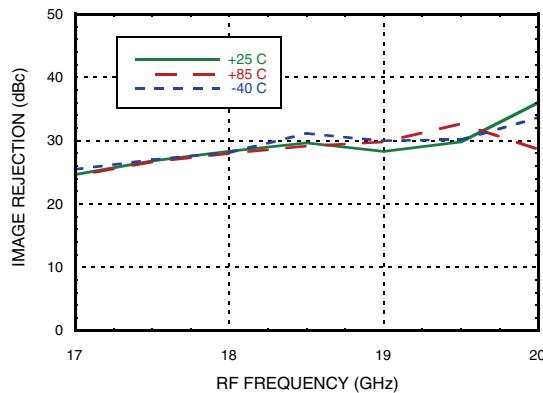
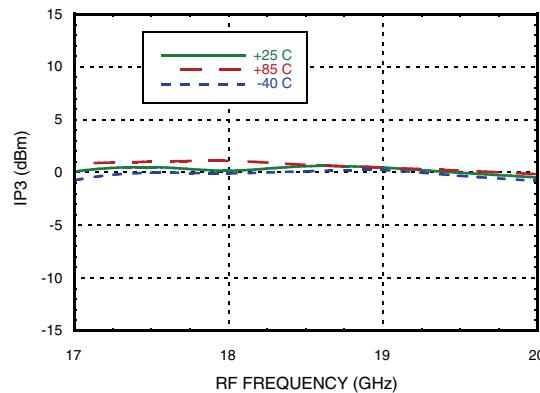
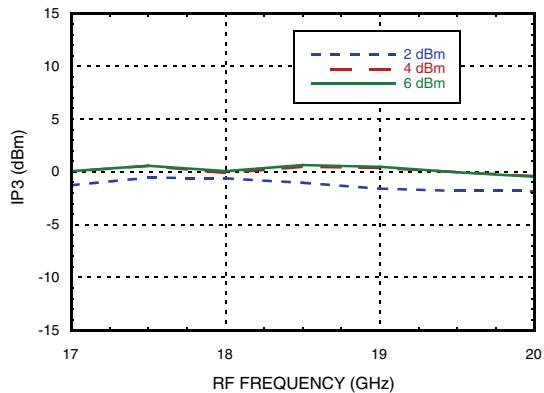


Input IP3, USB vs. LO Drive




**GAAS MMIC I/Q DOWNCONVERTER
17 - 20 GHz**

Data Taken as IRM With External IF 90° Hybrid, IF = 2000 MHz

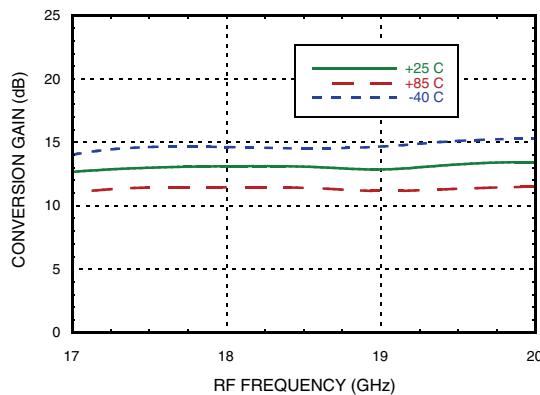
Conversion Gain, LSB vs. Temperature

Conversion Gain, LSB vs. LO Drive

Image Rejection vs. Temperature

Input IP3, LSB vs. Temperature

Input IP3, LSB vs. LO Drive




GAAS MMIC I/Q DOWNCONVERTER 17 - 20 GHz

Data Taken as IRM With External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

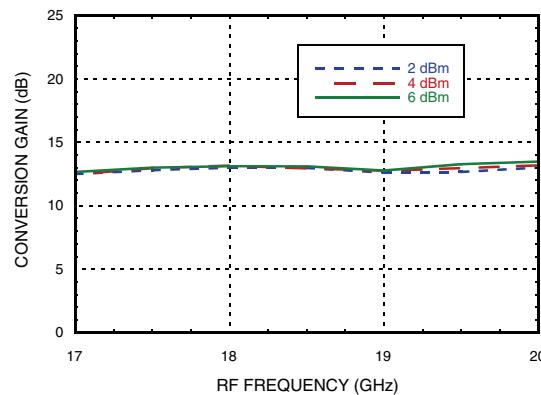
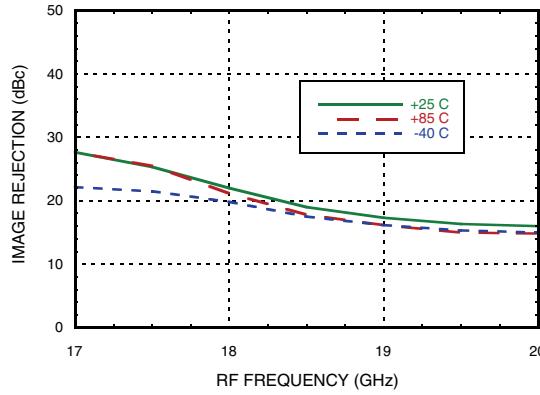
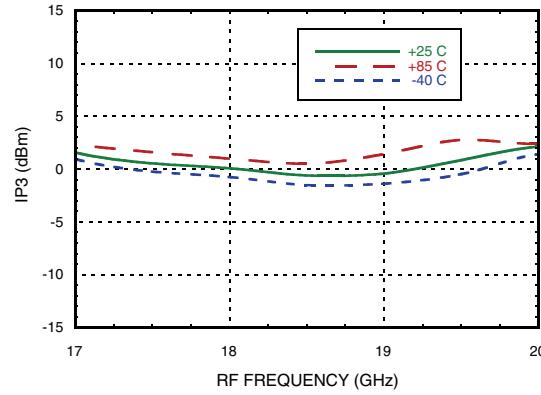


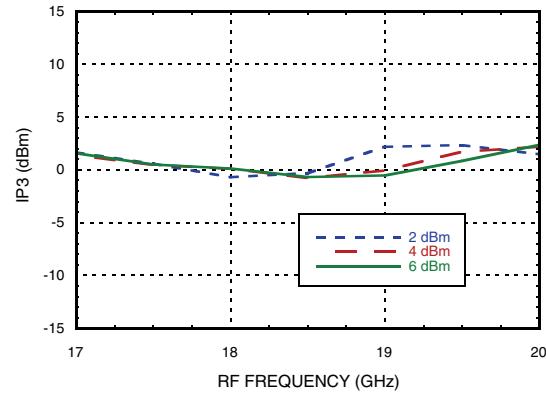
Image Rejection vs. Temperature



Input IP3, USB vs. Temperature

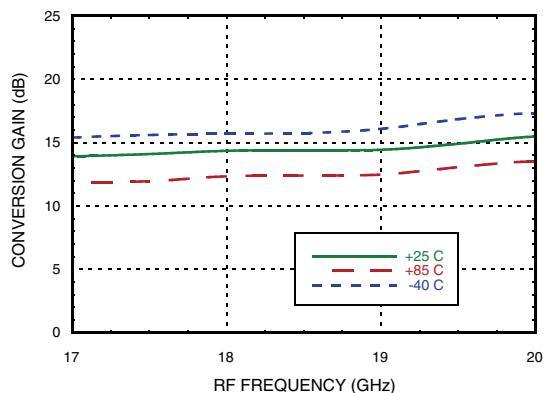
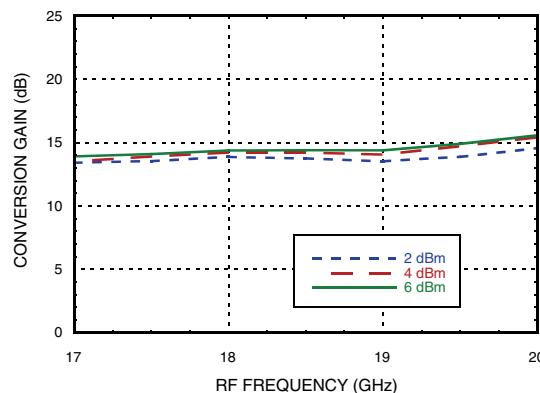
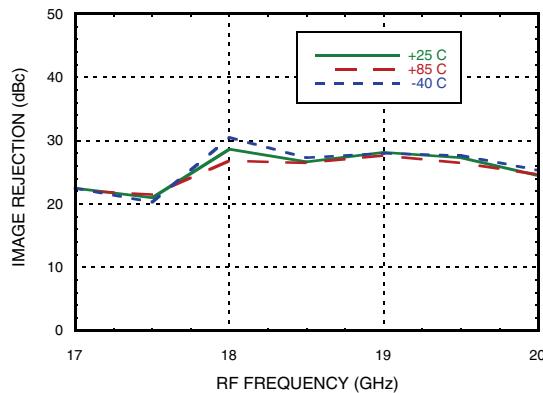
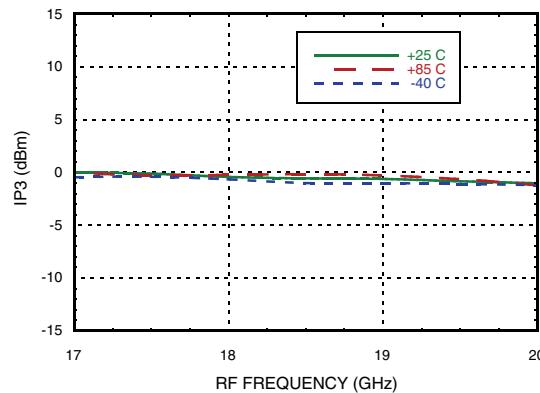
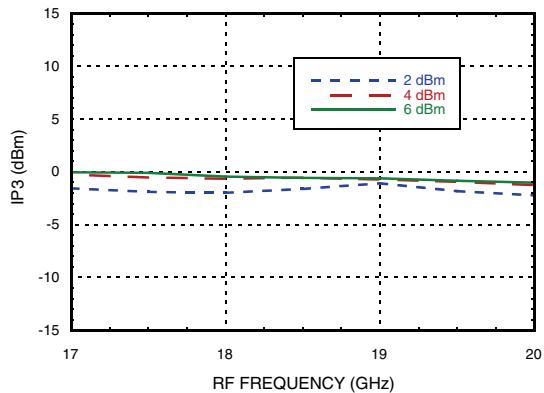


Input IP3, USB vs. LO Drive




**GAAS MMIC I/Q DOWNCONVERTER
17 - 20 GHz**

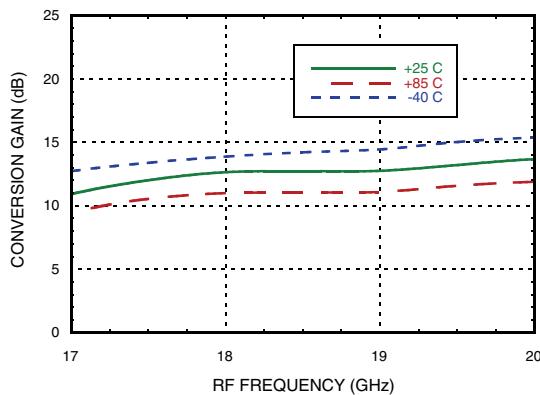
Data Taken as IRM With External IF 90° Hybrid, IF = 3300 MHz

Conversion Gain, LSB vs. Temperature

Conversion Gain, LSB vs. LO Drive

Image Rejection vs. Temperature

Input IP3, LSB vs. Temperature

Input IP3, LSB vs. LO Drive




Data Taken as IRM With External IF 90° Hybrid, IF = 3300 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

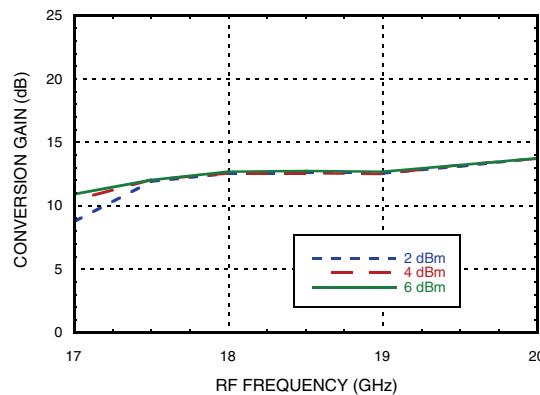
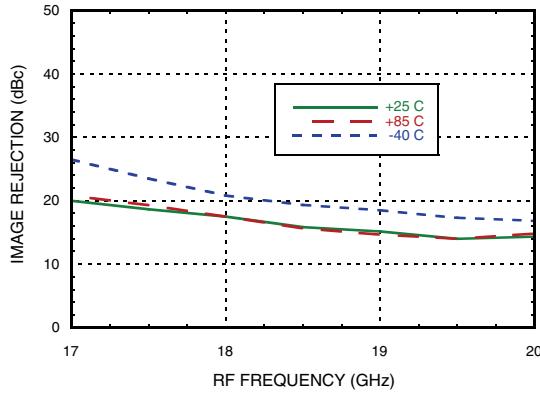
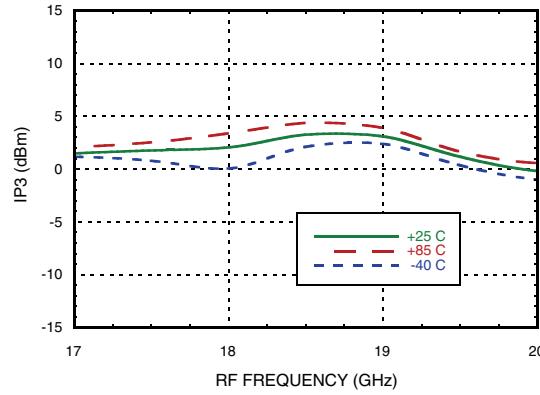


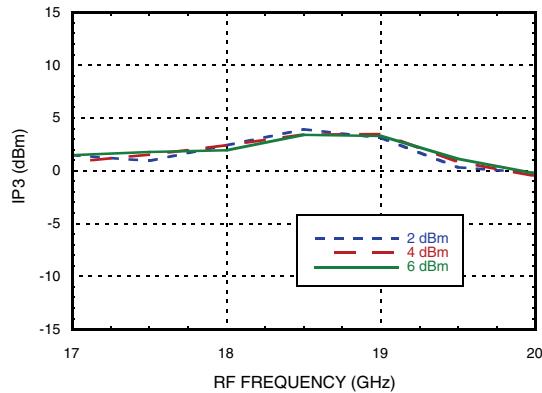
Image Rejection vs. Temperature



Input IP3, USB vs. Temperature



Input IP3, USB vs. LO Drive



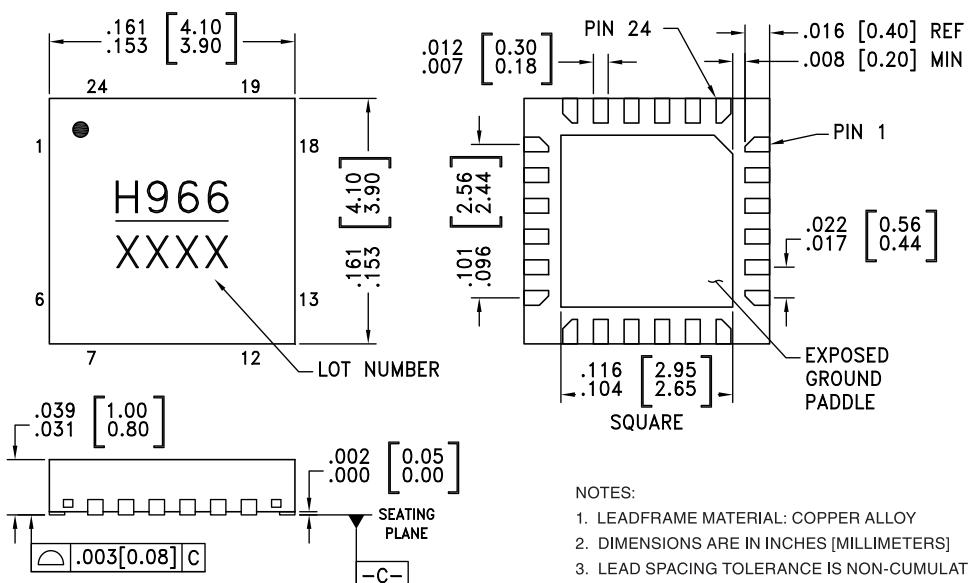

**GAAS MMIC I/Q DOWNCONVERTER
17 - 20 GHz**
MxN Spurious Outputs

	nLO				
mRF	0	1	2	3	4
0	x	-12.5	4.6	-18.7	-26.0
1	-10.7	-16.3	0	-16.7	-16
2	-53.4	-67.7	-42.1	-41.5	-39.9
3	x	-99.2	-82.9	-81.8	-73
4	x	x	x	-104.5	-99.1

RF = 18 GHz @ -20 dBm
 LO = 8.5 GHz @ +4 dBm
 Data taken without IF hybrid
 All values in dBc below IF power level (1RF -2LO = 1 GHz)

Absolute Maximum Ratings

RF	+10 dBm
LO Drive	+10 dBm
Vdd	4V
Channel Temperature	175 °C
Continuous Pdiss (T=85°C) (derate 16.4 mW/°C above 85°C)	1.48 W
Thermal Resistance (R_{TH}) (channel to package bottom)	60.7 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C
ESD Sensitivity (HBM)	Class 0


**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**
Outline Drawing

BOTTOM VIEW

NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
4. PAD BURR LENGTH SHALL BE 0.15 mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05 mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

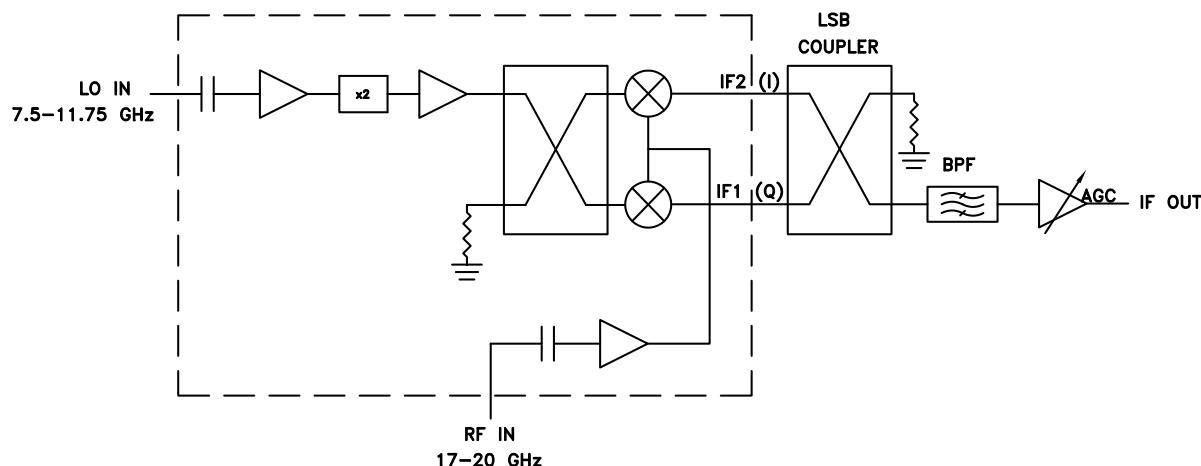
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[1]
HMC966LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H966 XXXX

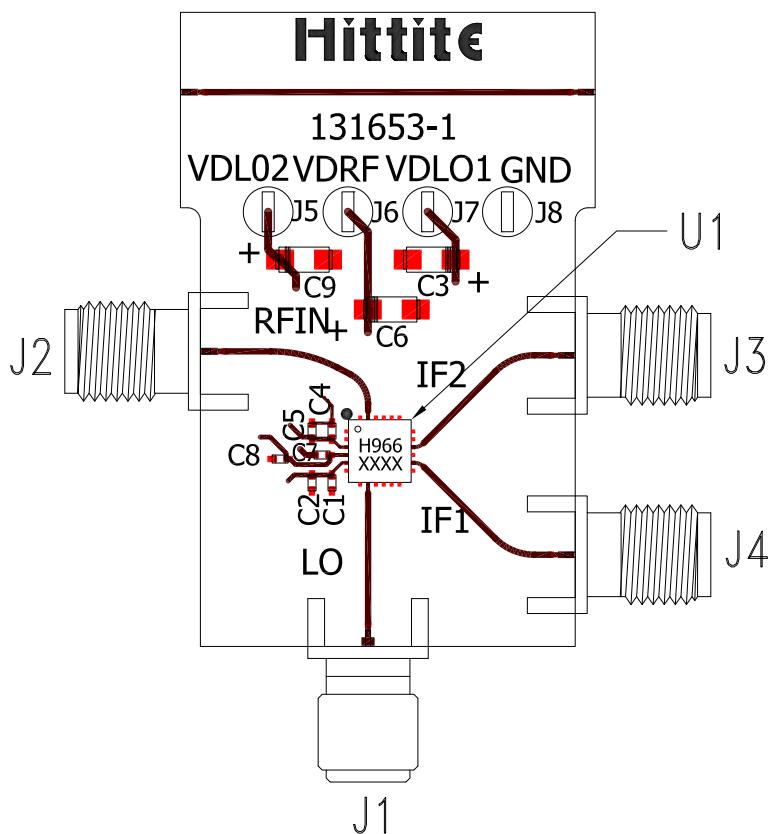
[1] 4-Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C


**GAAS MMIC I/Q DOWNCONVERTER
17 - 20 GHz**
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 6, 7, 10 - 12, 15, 18 - 22	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	VDRF	Power supply for RF LNA.	
4	VDLO2	Power supply for second stage of LO amplifier.	VDLO2 O --- ---
5	VDLO1	Power supply for first stage of LO amplifier.	VDLO1 O --- ---
8	LO	This pin is AC coupled and matched to 50 Ohms.	LO O --- ---
9, 13, 17, 24	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	GND O --- ---
16	IF2	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary frequency range. For operation to DC, this pin must not sink / source more than 3 mA of current or part non-function and possible failure will result.	IF1,IF2 O --- --- V --- --- V --- ---
14	IF1		
23	RF	This pin is AC coupled and matched to 50 Ohms	RF O --- ---

Typical Application Circuit



**GAAS MMIC I/Q DOWNCONVERTER
17 - 20 GHz**
Evaluation PCB

List of Materials for Evaluation PCB 131656^[1]

Item	Description
J1	PCB Mount SMA RF Connector, SRI
J2, J3	PCB Mount K Connector, SRI
J5 - J8	DC Pin
C1, C4, C7	100 pF Capacitor, 0402 Pkg.
C2, C5, C8	10 nF Capacitor, 0402 Pkg.
C3, C6, C9	4.7 μ F Capacitor, Case A Pkg.
U1	HMC966LP4E
PCB [2]	161653 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.